

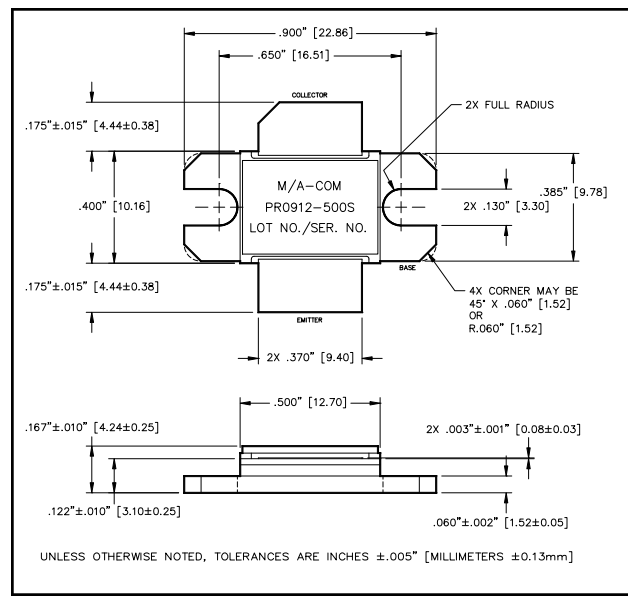
## Avionics Pulsed Power Transistor 500W, 960-1215 MHz, 10µs Pulse, 10% Duty

M/A-COM Products  
Released, 30 May 07

### Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

### Outline Drawing



### Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	$V_{CES}$	80	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current (Peak)	$I_C$	52.5	A
Power Dissipation @ +25°C	$P_{TOT}$	2.2	kW
Storage Temperature	$T_{STG}$	-65 to +200	°C
Junction Temperature	$T_J$	200	°C

### Electrical Specifications: $T_C = 25 \pm 5^\circ\text{C}$ (Room Ambient )

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	$I_C = 80\text{mA}$		$BV_{CES}$	80	-	V
Collector-Emitter Leakage Current	$V_{CE} = 40\text{V}$		$I_{CES}$	-	15	mA
Thermal Resistance	$V_{CC} = 50\text{V}$ , $P_{in} = 63\text{W}$	$F = 960, 1090, 1215\text{ MHz}$	$R_{TH(JC)}$	-	0.08	°C/W
Output Power	$V_{CC} = 50\text{V}$ , $P_{in} = 63\text{W}$	$F = 960, 1090, 1215\text{ MHz}$	$P_{OUT}$	500	-	W
Power Gain	$V_{CC} = 50\text{V}$ , $P_{in} = 63\text{W}$	$F = 960, 1090, 1215\text{ MHz}$	$G_P$	9.0	-	dB
Collector Efficiency	$V_{CC} = 50\text{V}$ , $P_{in} = 63\text{W}$	$F = 960, 1090, 1215\text{ MHz}$	$\eta_C$	45	-	%
Input Return Loss	$V_{CC} = 50\text{V}$ , $P_{in} = 63\text{W}$	$F = 960, 1090, 1215\text{ MHz}$	RL	-	-9	dB
Load Mismatch Tolerance	$V_{CC} = 50\text{V}$ , $P_{in} = 63\text{W}$	$F = 960\text{ MHz}$	VSWR-T	-	3:1	-
Load Mismatch Stability	$V_{CC} = 50\text{V}$ , $P_{in} = 63\text{W}$	$F = 960, 1090, 1215\text{ MHz}$	VSWR-S	-	1.5:1	-

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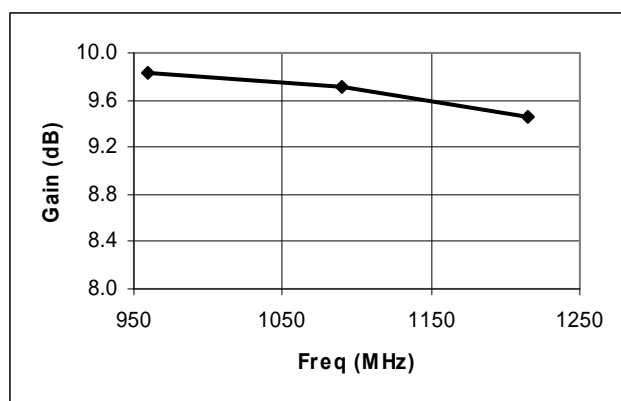
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## Typical RF Performance

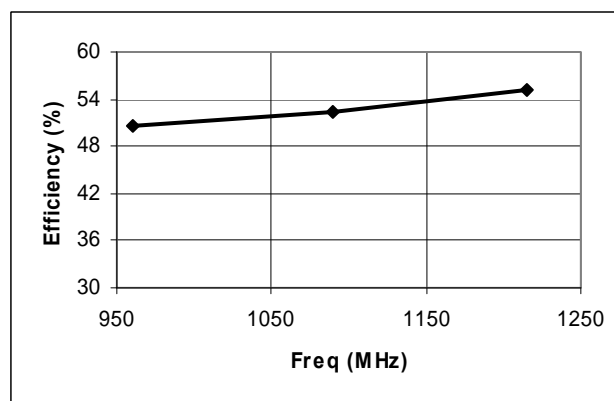
Freq. (MHz)	Pin (W)	Pout (W)	Gain (dB)	$\Delta$ Gain (dB)	Ic (A)	Eff (%)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)	P1dB Overdrive	
										Pout	$\Delta$ Po
960	63	598	9.77	-	23.5	50.9	-17.1	S	P	675	0.52
1090	63	582	9.65	-	21.9	53.1	-21.8	S	-	677	0.66
1215	63	554	9.44	0.33	19.7	56.1	-16.8	S	-	619	0.48

Note:  $\Delta$ Po(dB) is the difference between Pout at 1dB overdrive and Pout at Pin = 63W.

## Gain vs. Frequency



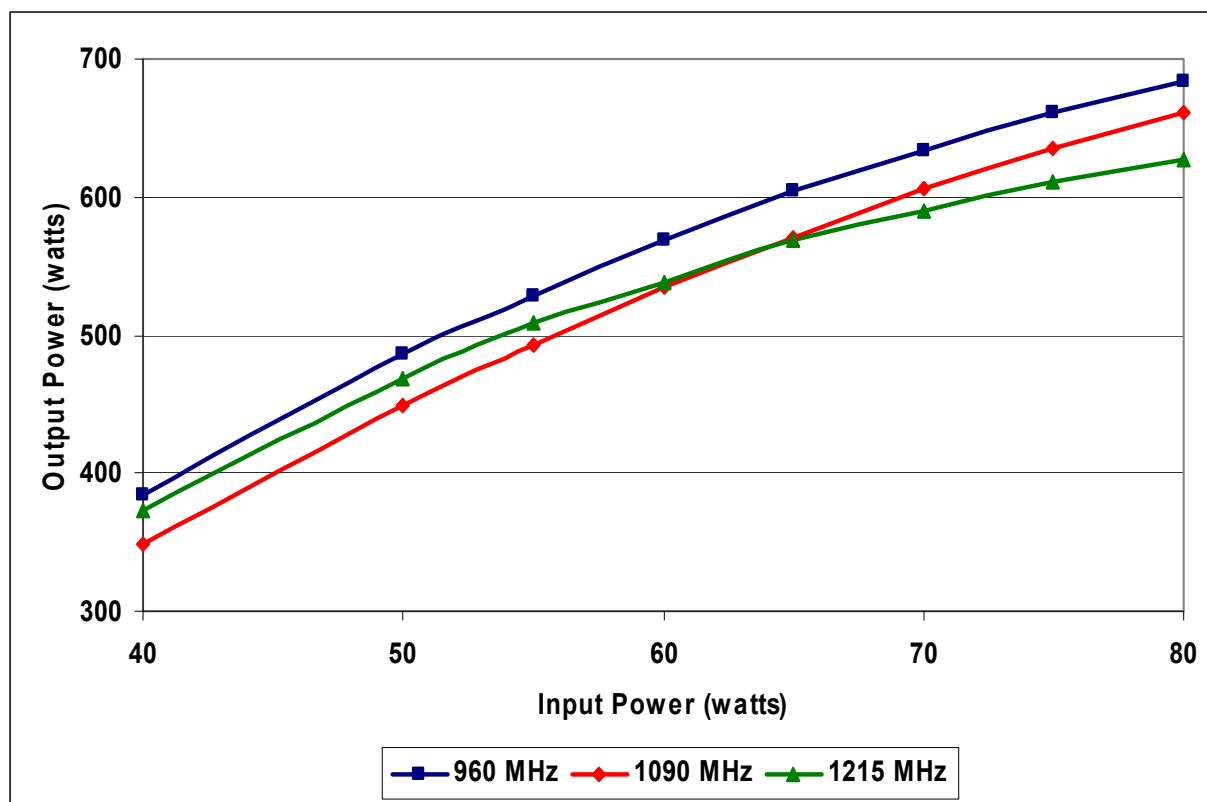
## Collector Efficiency vs. Frequency



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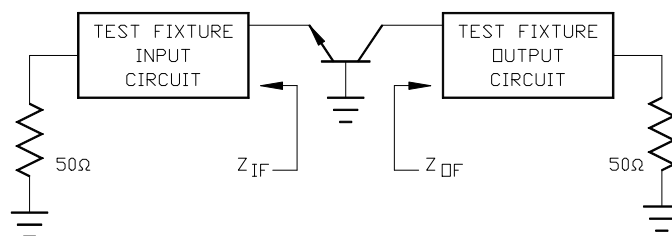
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## RF Power Transfer Curve (Output Power Vs. Input Power)



## Broadband Test Fixture Impedance

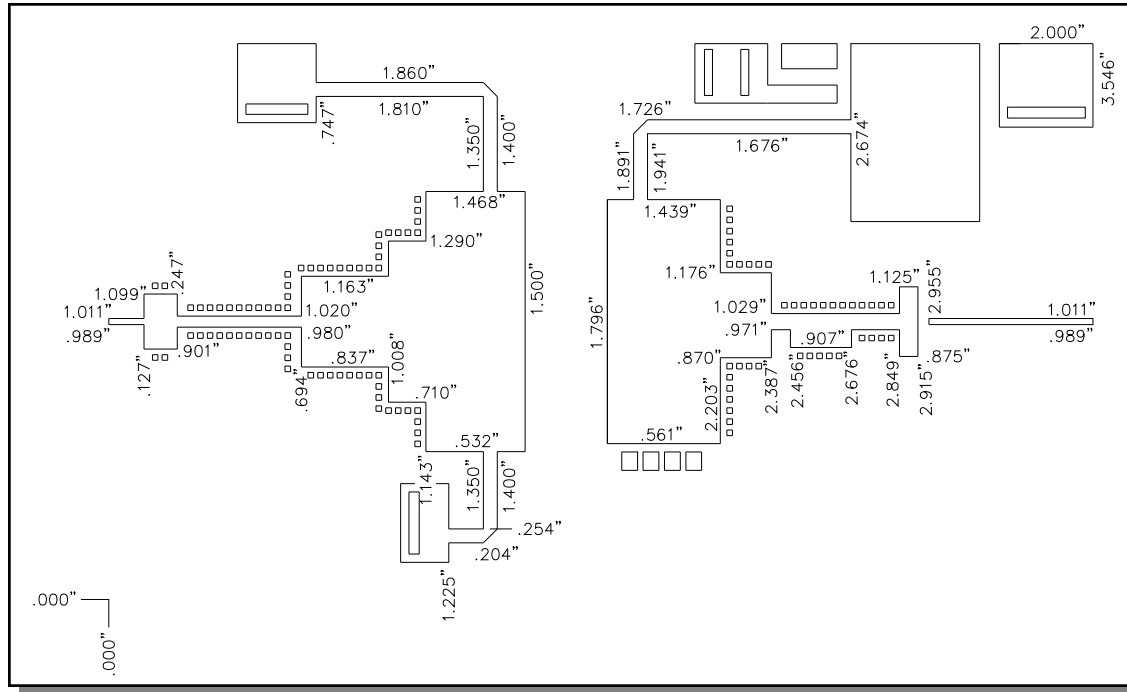
F (MHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)
960	1.3 - j1.4	1.2 - j1.4
1025	1.3 - j1.1	1.2 - j1.1
1090	1.2 - j0.9	1.3 - j0.9
1150	1.2 - j0.8	1.4 - j0.7
1215	1.0 - j0.8	1.3 - j0.6



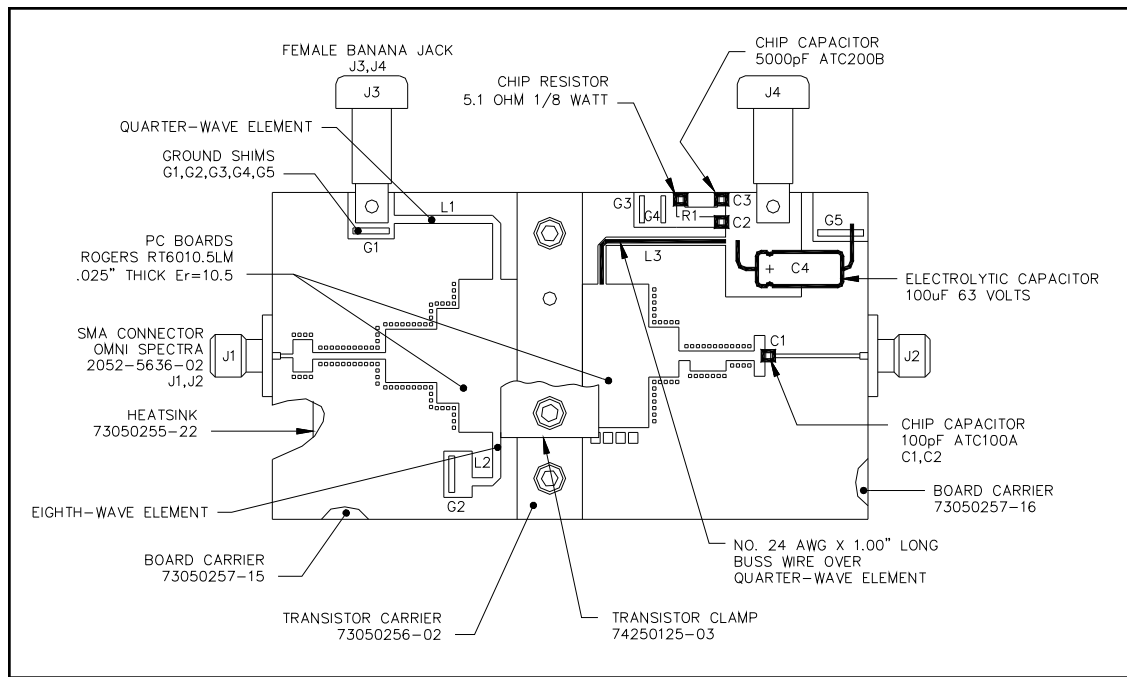
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## Test Fixture Circuit Dimensions



## Test Fixture Assembly



# AMEYA360

Components Supply Platform

Authorized Distribution Brand :



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